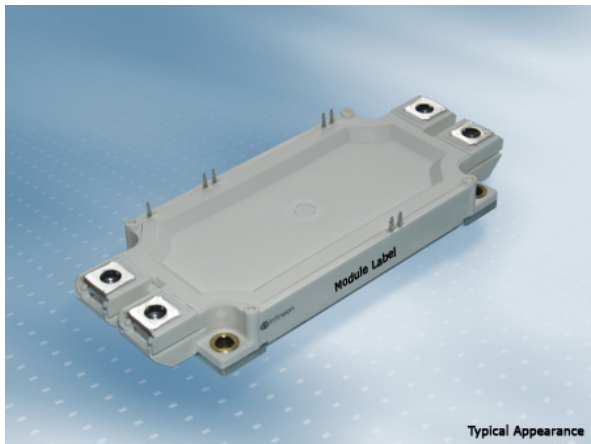


EconoDUAL™3 模块 采用第四代沟槽栅/场终止IGBT4和HE型发射极控制二极管 带有温度检测NTC  
EconoDUAL™3 module with Trench/Fieldstop IGBT4 and Emitter Controlled HE diode and NTC



$V_{CES} = 1200V$   
 $I_{C\ nom} = 300A / I_{CRM} = 600A$

### 典型应用

- 电机传动
- 伺服驱动器
- UPS系统
- 风力发电机

### Typical Applications

- Motor Drives
- Servo Drives
- UPS Systems
- Wind Turbines

### 电气特性

- 低  $V_{CEsat}$
- $T_{vj\ op} = 150^{\circ}C$

### Electrical Features

- Low  $V_{CEsat}$
- $T_{vj\ op} = 150^{\circ}C$

### 机械特性

- 标封装

### Mechanical Features

- Standard Housing

## Module Label Code

### Barcode Code 128



### DMX - Code



### Content of the Code

| Content of the Code        | Digit   |
|----------------------------|---------|
| Module Serial Number       | 1 - 5   |
| Module Material Number     | 6 - 11  |
| Production Order Number    | 12 - 19 |
| Datecode (Production Year) | 20 - 21 |
| Datecode (Production Week) | 22 - 23 |

|                 |                                 |                      |
|-----------------|---------------------------------|----------------------|
| prepared by: CU | date of publication: 2013-11-04 |                      |
| approved by: MK | revision: 3.1                   | UL approved (E83335) |

**IGBT, 逆变器 / IGBT, Inverter**

**最大额定值 / Maximum Rated Values**

|  |   |                            |            |        |
|--|---|----------------------------|------------|--------|
| 集电极 - 发射极电压<br>Collector-emitter voltage       | $T_{vj} = 25^{\circ}\text{C}$   | $V_{CES}$                  | 1200       | V      |
| 连续集电极直流电流<br>Continuous DC collector current   | $T_C = 100^{\circ}\text{C}, T_{vj\max} = 175^{\circ}\text{C}$<br>$T_C = 25^{\circ}\text{C}, T_{vj\max} = 175^{\circ}\text{C}$ | $I_{C\text{nom}}$<br>$I_C$ | 300<br>450 | A<br>A |
| 集电极重复峰值电流<br>Repetitive peak collector current | $t_P = 1\text{ ms}$   | $I_{CRM}$                  | 600        | A      |
| 总功率损耗<br>Total power dissipation               | $T_C = 25^{\circ}\text{C}, T_{vj\max} = 175^{\circ}\text{C}$  | $P_{\text{tot}}$           | 1600       | W      |
| 栅极 - 发射极峰值电压<br>Gate-emitter peak voltage      |   | $V_{GES}$                  | +/-20      | V      |

**特征值 / Characteristic Values**

|   |   |   | min.               | typ.                 | max. |             |   |
|---|---|---|--------------------|----------------------|------|-------------|---|
| 集电极 - 发射极饱和电压<br>Collector-emitter saturation voltage | $I_C = 300\text{ A}, V_{GE} = 15\text{ V}$<br>$I_C = 300\text{ A}, V_{GE} = 15\text{ V}$<br>$I_C = 300\text{ A}, V_{GE} = 15\text{ V}$  | $T_{vj} = 25^{\circ}\text{C}$<br>$T_{vj} = 125^{\circ}\text{C}$<br>$T_{vj} = 150^{\circ}\text{C}$ | $V_{CE\text{sat}}$ | 1,75<br>2,00<br>2,05 | 2,10 | V<br>V<br>V |   |
| 栅极阈值电压<br>Gate threshold voltage                      | $I_C = 11,5\text{ mA}, V_{CE} = V_{GE}, T_{vj} = 25^{\circ}\text{C}$  |   | $V_{GEth}$         | 5,2                  | 5,8  | 6,4         | V   |
| 栅极电荷<br>Gate charge                                   | $V_{GE} = -15\text{ V} \dots +15\text{ V}$  |   | $Q_G$              | 2,25                 |      |             | $\mu\text{C}$                                   |
| 内部栅极电阻<br>Internal gate resistor                      | $T_{vj} = 25^{\circ}\text{C}$   |   | $R_{Gint}$         | 2,5                  |      |             | $\Omega$  |
| 输入电容<br>Input capacitance                             | $f = 1\text{ MHz}, T_{vj} = 25^{\circ}\text{C}, V_{CE} = 25\text{ V}, V_{GE} = 0\text{ V}$  |   | $C_{ies}$          | 18,5                 |      |             | nF  |
| 反向传输电容<br>Reverse transfer capacitance                | $f = 1\text{ MHz}, T_{vj} = 25^{\circ}\text{C}, V_{CE} = 25\text{ V}, V_{GE} = 0\text{ V}$  |   | $C_{res}$          | 1,05                 |      |             | nF  |
| 集电极-发射极截止电流<br>Collector-emitter cut-off current      | $V_{CE} = 1200\text{ V}, V_{GE} = 0\text{ V}, T_{vj} = 25^{\circ}\text{C}$  |   | $I_{CES}$          |                      |      | 3,0         | mA  |
| 栅极-发射极漏电流<br>Gate-emitter leakage current             | $V_{CE} = 0\text{ V}, V_{GE} = 20\text{ V}, T_{vj} = 25^{\circ}\text{C}$  |   | $I_{GES}$          |                      |      | 400         | nA  |
| 开通延迟时间(电感负载)<br>Turn-on delay time, inductive load    | $I_C = 300\text{ A}, V_{CE} = 600\text{ V}$<br>$V_{GE} = \pm 15\text{ V}$<br>$R_{Gon} = 1,3\ \Omega$  | $T_{vj} = 25^{\circ}\text{C}$<br>$T_{vj} = 125^{\circ}\text{C}$<br>$T_{vj} = 150^{\circ}\text{C}$ | $t_{don}$          | 0,17<br>0,18<br>0,19 |      |             | $\mu\text{s}$<br>$\mu\text{s}$<br>$\mu\text{s}$ |
| 上升时间(电感负载)<br>Rise time, inductive load               | $I_C = 300\text{ A}, V_{CE} = 600\text{ V}$<br>$V_{GE} = \pm 15\text{ V}$<br>$R_{Gon} = 1,3\ \Omega$  | $T_{vj} = 25^{\circ}\text{C}$<br>$T_{vj} = 125^{\circ}\text{C}$<br>$T_{vj} = 150^{\circ}\text{C}$ | $t_r$              | 0,05<br>0,05<br>0,05 |      |             | $\mu\text{s}$<br>$\mu\text{s}$<br>$\mu\text{s}$ |
| 关断延迟时间(电感负载)<br>Turn-off delay time, inductive load   | $I_C = 300\text{ A}, V_{CE} = 600\text{ V}$<br>$V_{GE} = \pm 15\text{ V}$<br>$R_{Goff} = 1,3\ \Omega$   | $T_{vj} = 25^{\circ}\text{C}$<br>$T_{vj} = 125^{\circ}\text{C}$<br>$T_{vj} = 150^{\circ}\text{C}$ | $t_{doff}$         | 0,45<br>0,56<br>0,60 |      |             | $\mu\text{s}$<br>$\mu\text{s}$<br>$\mu\text{s}$ |
| 下降时间(电感负载)<br>Fall time, inductive load               | $I_C = 300\text{ A}, V_{CE} = 600\text{ V}$<br>$V_{GE} = \pm 15\text{ V}$<br>$R_{Goff} = 1,3\ \Omega$   | $T_{vj} = 25^{\circ}\text{C}$<br>$T_{vj} = 125^{\circ}\text{C}$<br>$T_{vj} = 150^{\circ}\text{C}$ | $t_f$              | 0,07<br>0,11<br>0,12 |      |             | $\mu\text{s}$<br>$\mu\text{s}$<br>$\mu\text{s}$ |
| 开通损耗能量(每脉冲)<br>Turn-on energy loss per pulse          | $I_C = 300\text{ A}, V_{CE} = 600\text{ V}, L_S = 80\text{ nH}$<br>$V_{GE} = \pm 15\text{ V}, di/dt = 6050\text{ A}/\mu\text{s} (T_{vj} = 150^{\circ}\text{C})$<br>$R_{Gon} = 1,3\ \Omega$  | $T_{vj} = 25^{\circ}\text{C}$<br>$T_{vj} = 125^{\circ}\text{C}$<br>$T_{vj} = 150^{\circ}\text{C}$ | $E_{on}$           | 9,90<br>17,0<br>19,5 |      |             | mJ<br>mJ<br>mJ                                  |
| 关断损耗能量(每脉冲)<br>Turn-off energy loss per pulse         | $I_C = 300\text{ A}, V_{CE} = 600\text{ V}, L_S = 80\text{ nH}$<br>$V_{GE} = \pm 15\text{ V}, du/dt = 3100\text{ V}/\mu\text{s} (T_{vj} = 150^{\circ}\text{C})$<br>$R_{Goff} = 1,3\ \Omega$ | $T_{vj} = 25^{\circ}\text{C}$<br>$T_{vj} = 125^{\circ}\text{C}$<br>$T_{vj} = 150^{\circ}\text{C}$ | $E_{off}$          | 25,0<br>37,5<br>42,0 |      |             | mJ<br>mJ<br>mJ                                  |
| 短路数据<br>SC data                                       | $V_{GE} \leq 15\text{ V}, V_{CC} = 800\text{ V}$<br>$V_{CE\text{max}} = V_{CES} - L_{SCE} \cdot di/dt$ $t_P \leq 10\ \mu\text{s}, T_{vj} = 150^{\circ}\text{C}$                             |   | $I_{SC}$           | 1200                 |      |             | A   |
| 结 - 外壳热阻<br>Thermal resistance, junction to case      | 每个 IGBT / per IGBT  |   | $R_{thJC}$         |                      |      | 0,094       | K/W   |
| 外壳 - 散热器热阻<br>Thermal resistance, case to heatsink    | 每个 IGBT / per IGBT<br>$\lambda_{\text{Paste}} = 1\text{ W}/(\text{m}\cdot\text{K})$ / $\lambda_{\text{grease}} = 1\text{ W}/(\text{m}\cdot\text{K})$  |   | $R_{thCH}$         | 0,03                 |      |             | K/W   |
| 在开关状态下温度<br>Temperature under switching conditions    |   |   | $T_{vj\text{op}}$  | -40                  |      | 150         | $^{\circ}\text{C}$                              |

|                 |                                 |
|-----------------|---------------------------------|
| prepared by: CU | date of publication: 2013-11-04 |
| approved by: MK | revision: 3.1                   |

**二极管, 逆变器 / Diode, Inverter**  
**最大额定值 / Maximum Rated Values**

|   |  |           |                |  |
|---|--|-----------|----------------|--|
| 反向重复峰值电压<br>Repetitive peak reverse voltage | $T_{vj} = 25^{\circ}\text{C}$  | $V_{RRM}$ | 1200           | V  |
| 连续正向直流电流<br>Continuous DC forward current   |  | $I_F$     | 300            | A  |
| 正向重复峰值电流<br>Repetitive peak forward current | $t_P = 1\text{ ms}$  | $I_{FRM}$ | 600            | A  |
| $I_{2t}$ -值<br>$I_{2t}$ -value              | $V_R = 0\text{ V}, t_P = 10\text{ ms}, T_{vj} = 125^{\circ}\text{C}$<br>$V_R = 0\text{ V}, t_P = 10\text{ ms}, T_{vj} = 150^{\circ}\text{C}$ | $I_{2t}$  | 19000<br>15500 | $\text{A}^2\text{s}$<br>$\text{A}^2\text{s}$ |

**特征值 / Characteristic Values**

|  |  |   | min.               | typ.                 | max. |   |
|--|--|---|--------------------|----------------------|------|---|
| 正向电压<br>Forward voltage                            | $I_F = 300\text{ A}, V_{GE} = 0\text{ V}$<br>$I_F = 300\text{ A}, V_{GE} = 0\text{ V}$<br>$I_F = 300\text{ A}, V_{GE} = 0\text{ V}$        | $T_{vj} = 25^{\circ}\text{C}$<br>$T_{vj} = 125^{\circ}\text{C}$<br>$T_{vj} = 150^{\circ}\text{C}$ | $V_F$              | 1,65<br>1,65<br>1,65 | 2,10 | V<br>V<br>V                                     |
| 反向恢复峰值电流<br>Peak reverse recovery current          | $I_F = 300\text{ A}, -di_F/dt = 6050\text{ A}/\mu\text{s} (T_{vj}=150^{\circ}\text{C})$<br>$V_R = 600\text{ V}$<br>$V_{GE} = -15\text{ V}$ | $T_{vj} = 25^{\circ}\text{C}$<br>$T_{vj} = 125^{\circ}\text{C}$<br>$T_{vj} = 150^{\circ}\text{C}$ | $I_{RM}$           | 335<br>390<br>410    |      | A<br>A<br>A                                     |
| 恢复电荷<br>Recovered charge                           | $I_F = 300\text{ A}, -di_F/dt = 6050\text{ A}/\mu\text{s} (T_{vj}=150^{\circ}\text{C})$<br>$V_R = 600\text{ V}$<br>$V_{GE} = -15\text{ V}$ | $T_{vj} = 25^{\circ}\text{C}$<br>$T_{vj} = 125^{\circ}\text{C}$<br>$T_{vj} = 150^{\circ}\text{C}$ | $Q_r$              | 30,5<br>58,0<br>67,0 |      | $\mu\text{C}$<br>$\mu\text{C}$<br>$\mu\text{C}$ |
| 反向恢复损耗 (每脉冲)<br>Reverse recovery energy            | $I_F = 300\text{ A}, -di_F/dt = 6050\text{ A}/\mu\text{s} (T_{vj}=150^{\circ}\text{C})$<br>$V_R = 600\text{ V}$<br>$V_{GE} = -15\text{ V}$ | $T_{vj} = 25^{\circ}\text{C}$<br>$T_{vj} = 125^{\circ}\text{C}$<br>$T_{vj} = 150^{\circ}\text{C}$ | $E_{rec}$          | 19,0<br>29,5<br>34,5 |      | mJ<br>mJ<br>mJ                                  |
| 结 - 外壳热阻<br>Thermal resistance, junction to case   | 每个二极管 / per diode  |   | $R_{thJC}$         |                      | 0,15 | K/W   |
| 外壳 - 散热器热阻<br>Thermal resistance, case to heatsink | 每个二极管 / per diode<br>$\lambda_{Paste} = 1\text{ W}/(\text{m}\cdot\text{K}) / \lambda_{grease} = 1\text{ W}/(\text{m}\cdot\text{K})$        |   | $R_{thCH}$         | 0,046                |      | K/W   |
| 在开关状态下温度<br>Temperature under switching conditions |  |   | $T_{vj\text{ op}}$ | -40                  | 150  | $^{\circ}\text{C}$                              |

**负温度系数热敏电阻 / NTC-Thermistor**

**特征值 / Characteristic Values**

|                              |   |  | min.         | typ. | max. |                  |
|------------------------------|---|--|--------------|------|------|------------------|
| 额定电阻值<br>Rated resistance    | $T_C = 25^{\circ}\text{C}$                                    |  | $R_{25}$     | 5,00 |      | $\text{k}\Omega$ |
| R100 偏差<br>Deviation of R100 | $T_C = 100^{\circ}\text{C}, R_{100} = 493\ \Omega$            |  | $\Delta R/R$ | -5   | 5    | %                |
| 耗散功率<br>Power dissipation    | $T_C = 25^{\circ}\text{C}$                                    |  | $P_{25}$     |      | 20,0 | mW               |
| B-值<br>B-value               | $R_2 = R_{25} \exp [B_{25/50}(1/T_2 - 1/(298,15\text{ K}))]$  |  | $B_{25/50}$  | 3375 |      | K                |
| B-值<br>B-value               | $R_2 = R_{25} \exp [B_{25/80}(1/T_2 - 1/(298,15\text{ K}))]$  |  | $B_{25/80}$  | 3411 |      | K                |
| B-值<br>B-value               | $R_2 = R_{25} \exp [B_{25/100}(1/T_2 - 1/(298,15\text{ K}))]$ |  | $B_{25/100}$ | 3433 |      | K                |

根据应用手册标定

Specification according to the valid application note.

|                 |                                 |
|-----------------|---------------------------------|
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**模块 / Module**

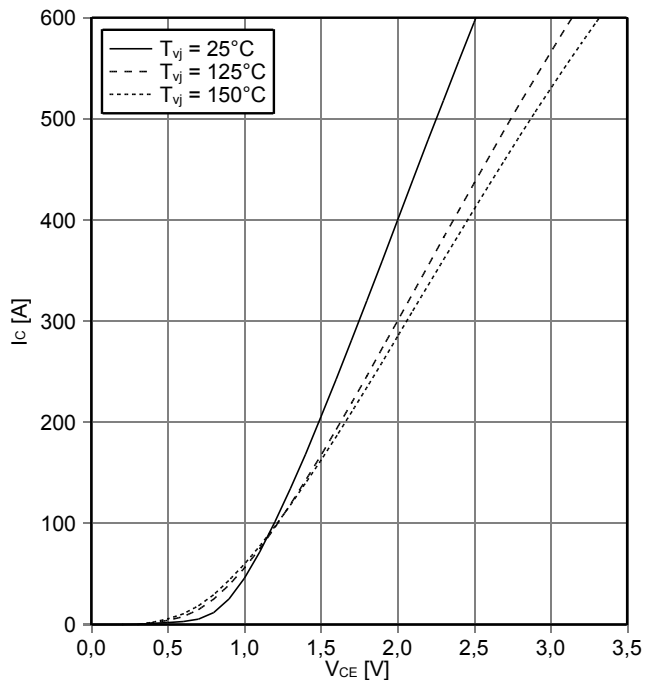
|  |   |                     |                                |     |         |
|--|---|---------------------|--------------------------------|-----|---------|
| 绝缘测试电压<br>Isolation test voltage                           | RMS, f = 50 Hz, t = 1 min   | V <sub>ISOL</sub>   | 2,5                            |     | kV      |
| 模块基板材料<br>Material of module baseplate                     |   |                     | Cu                             |     |         |
| 内部绝缘<br>Internal isolation                                 | 基本绝缘 (class 1, IEC 61140)<br>basic insulation (class 1, IEC 61140)  |                     | Al <sub>2</sub> O <sub>3</sub> |     |         |
| 爬电距离<br>Creepage distance                                  | 端子- 散热片 / terminal to heatsink<br>端子- 端子 / terminal to terminal   |                     | 14,5<br>13,0                   |     | mm      |
| 电气间隙<br>Clearance  | 端子- 散热片 / terminal to heatsink<br>端子- 端子 / terminal to terminal   |                     | 12,5<br>10,0                   |     | mm      |
| 相对电痕指数<br>Comperative tracking index                       |   | CTI                 | > 200                          |     |         |
| min.    typ.    max.                                       |   |                     |                                |     |         |
| 外壳 - 散热器热阻<br>Thermal resistance, case to heatsink         | 每个模块 / per module<br>$\lambda_{\text{Paste}} = 1 \text{ W/(m}\cdot\text{K)} / \lambda_{\text{grease}} = 1 \text{ W/(m}\cdot\text{K)}$ | R <sub>thCH</sub>   | 0,009                          |     | K/W     |
| 杂散电感, 模块<br>Stray inductance module                        |   | L <sub>sCE</sub>    | 20                             |     | nH      |
| 模块引线电阻, 端子- 芯片<br>Module lead resistance, terminals - chip | T <sub>C</sub> = 25°C, 每个开关 / per switch  | R <sub>CC+EE'</sub> | 1,20                           |     | mΩ      |
| 储存温度<br>Storage temperature                                |   | T <sub>stg</sub>    | -40                            | 125 | °C      |
| 模块安装的安装扭矩<br>Mounting torque for modul mounting            | 螺丝 M5 根据相应的应用手册进行安装<br>Screw M5 - Mounting according to valid application note  | M                   | 3,00                           | -   | 6,00 Nm |
| 端子联接扭矩<br>Terminal connection torque                       | 螺丝 M6 根据相应的应用手册进行安装<br>Screw M6 - Mounting according to valid application note  | M                   | 3,0                            | -   | 6,0 Nm  |
| 重量<br>Weight   |   | G                   | 345                            |     | g       |

|                 |                                 |
|-----------------|---------------------------------|
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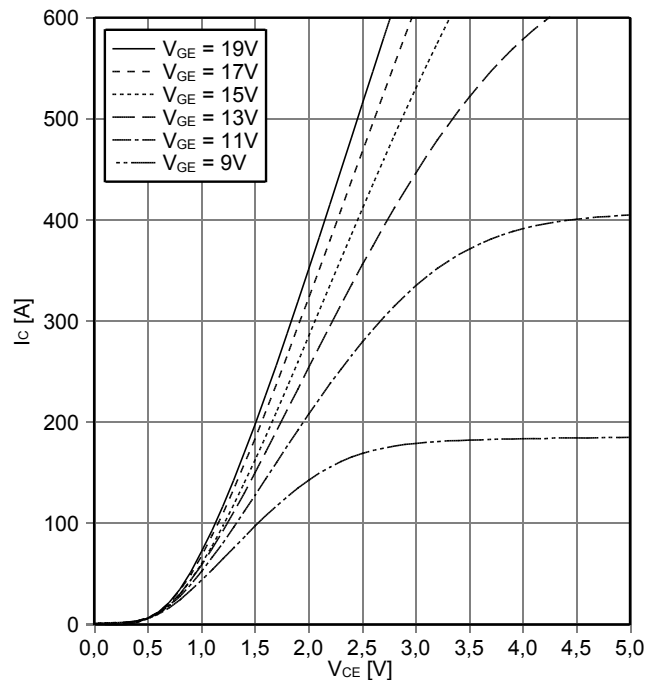
输出特性 IGBT, 逆变器 (典型)  
output characteristic IGBT, Inverter (typical)

$I_C = f(V_{CE})$   
 $V_{GE} = 15\text{ V}$



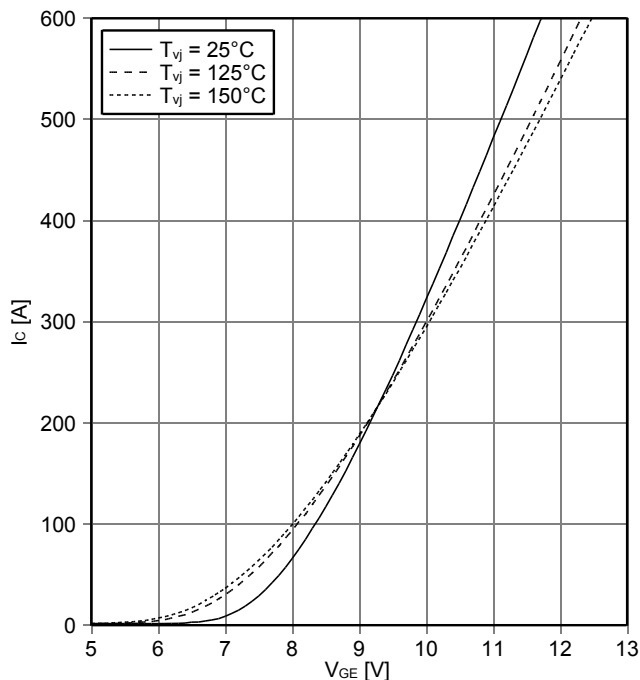
输出特性 IGBT, 逆变器 (典型)  
output characteristic IGBT, Inverter (typical)

$I_C = f(V_{CE})$   
 $T_{vj} = 150^\circ\text{C}$



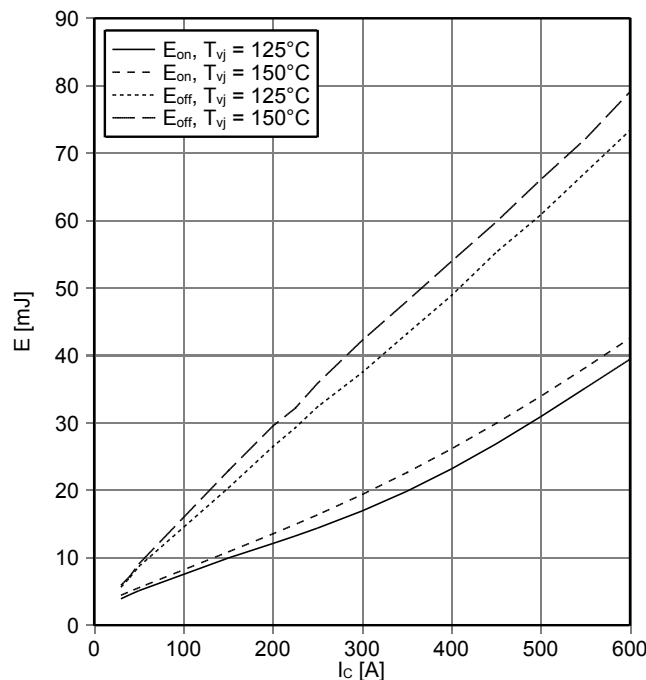
传输特性 IGBT, 逆变器 (典型)  
transfer characteristic IGBT, Inverter (typical)

$I_C = f(V_{GE})$   
 $V_{CE} = 20\text{ V}$



开关损耗 IGBT, 逆变器 (典型)  
switching losses IGBT, Inverter (typical)

$E_{on} = f(I_C), E_{off} = f(I_C)$   
 $V_{GE} = \pm 15\text{ V}, R_{Gon} = 1.3\ \Omega, R_{Goff} = 1.3\ \Omega, V_{CE} = 600\text{ V}$

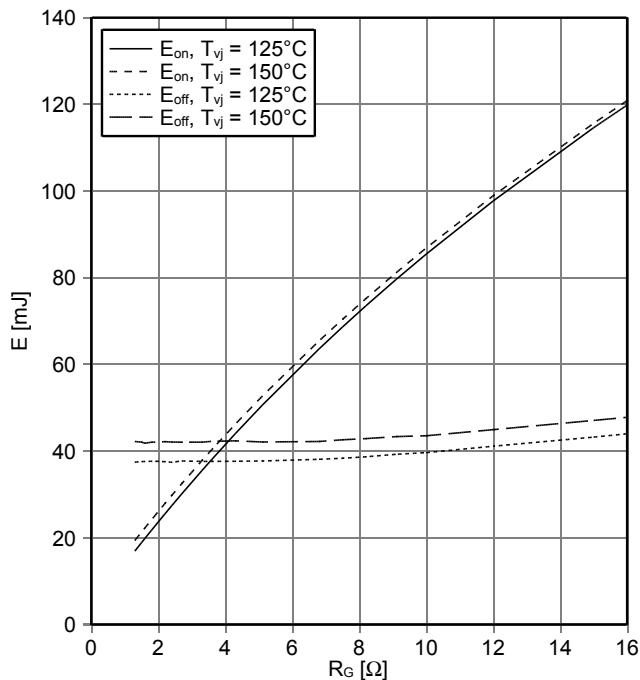


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| prepared by: CU | date of publication: 2013-11-04 |
| approved by: MK | revision: 3.1                   |



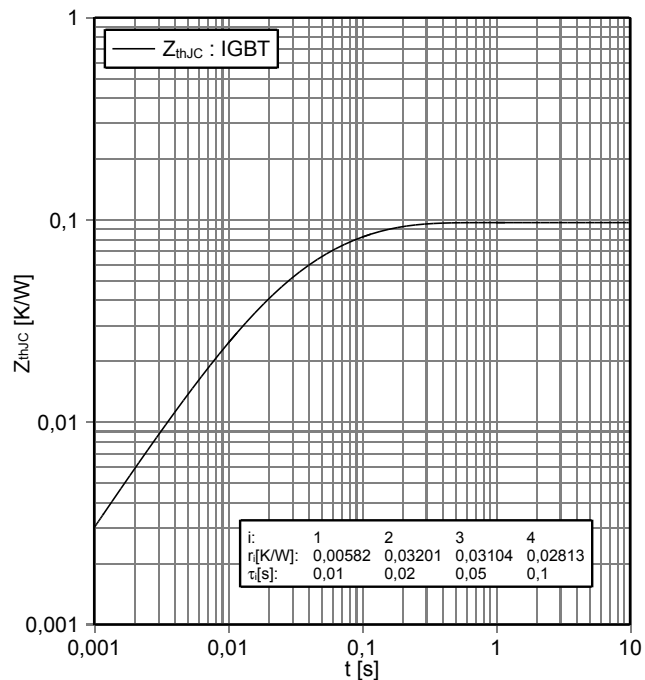
开关损耗 IGBT, 逆变器 (典型)  
switching losses IGBT, Inverter (typical)

$E_{on} = f(R_G), E_{off} = f(R_G)$   
 $V_{GE} = \pm 15\text{ V}, I_C = 300\text{ A}, V_{CE} = 600\text{ V}$



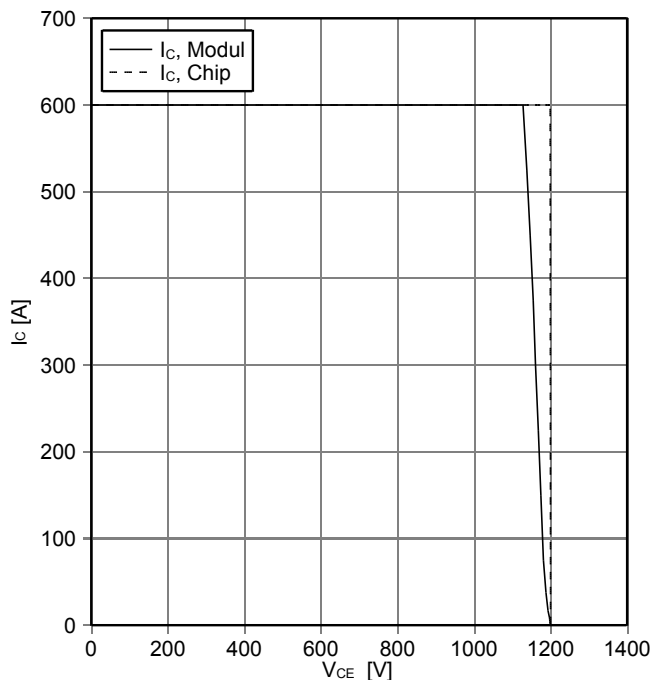
瞬态热阻抗 IGBT, 逆变器  
transient thermal impedance IGBT, Inverter

$Z_{thJC} = f(t)$



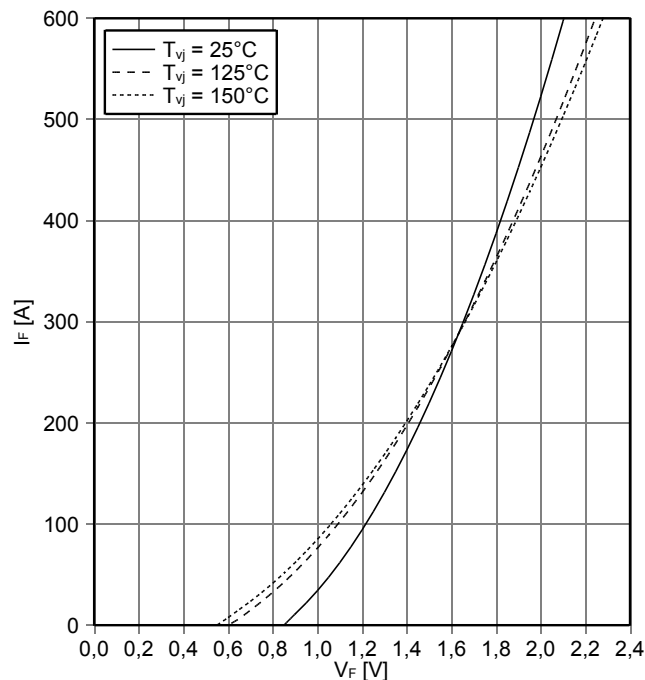
反偏安全工作区 IGBT, 逆变器 (RBSOA)  
reverse bias safe operating area IGBT, Inverter (RBSOA)

$I_C = f(V_{CE})$   
 $V_{GE} = \pm 15\text{ V}, R_{Goff} = 1.3\ \Omega, T_{vj} = 150^\circ\text{C}$



正向偏压特性 二极管, 逆变器 (典型)  
forward characteristic of Diode, Inverter (typical)

$I_F = f(V_F)$

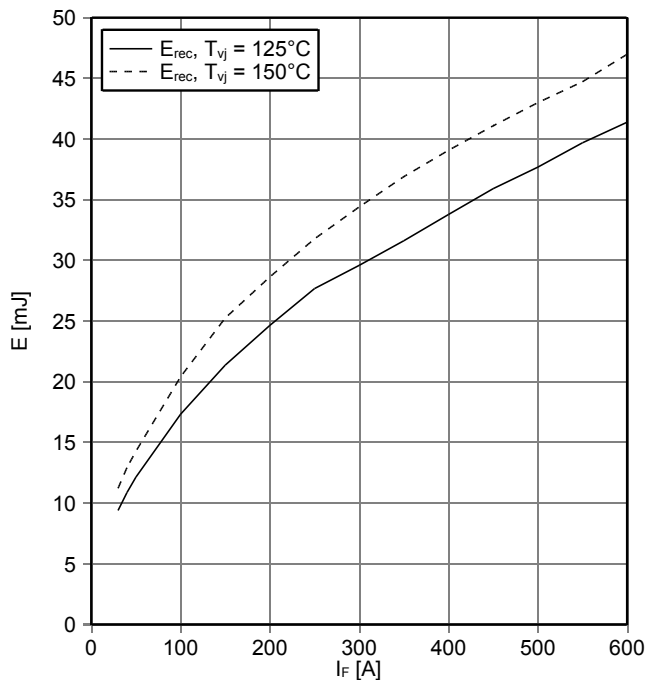


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|-----------------|---------------------------------|
| prepared by: CU | date of publication: 2013-11-04 |
| approved by: MK | revision: 3.1                   |



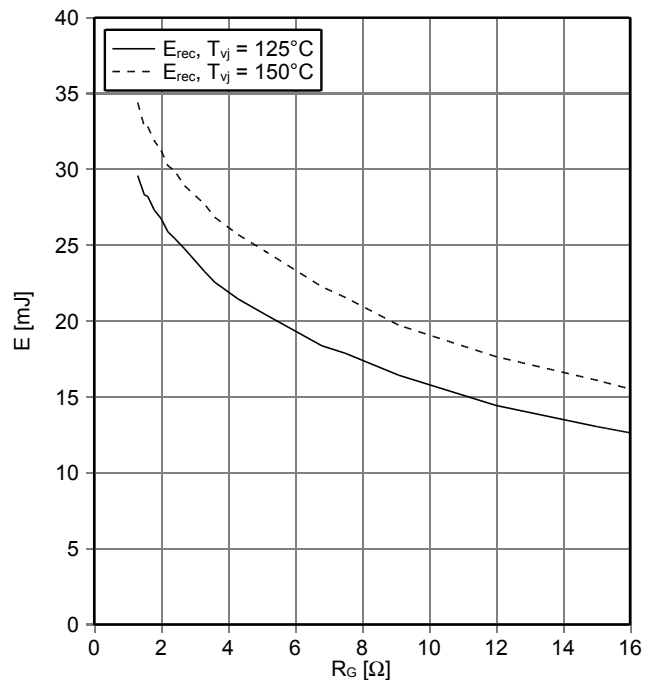
开关损耗 二极管,逆变器 (典型)  
switching losses Diode, Inverter (typical)

$E_{rec} = f(I_F)$   
 $R_{Gon} = 1.3 \Omega, V_{CE} = 600 V$



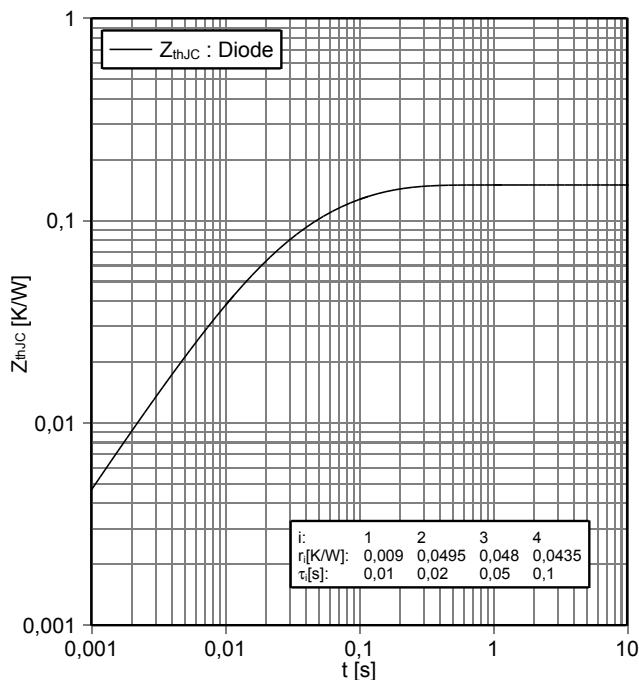
开关损耗 二极管,逆变器 (典型)  
switching losses Diode, Inverter (typical)

$E_{rec} = f(R_G)$   
 $I_F = 300 A, V_{CE} = 600 V$



瞬态热阻抗 二极管,逆变器  
transient thermal impedance Diode, Inverter

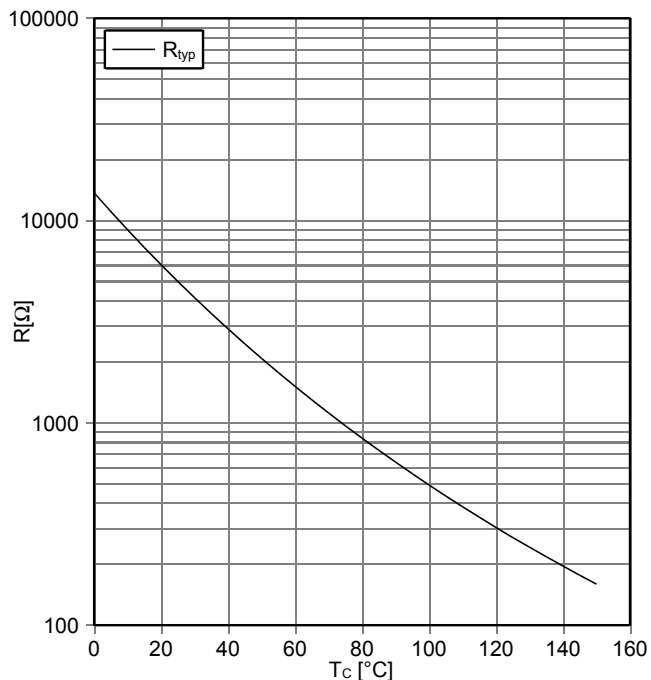
$Z_{thJC} = f(t)$



负温度系数热敏电阻 温度特性

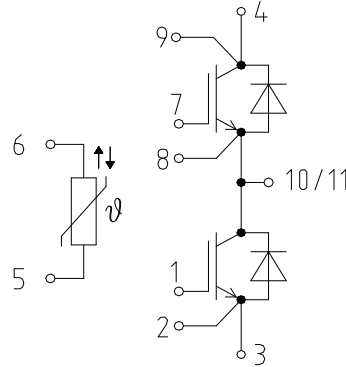
NTC-Thermistor-temperature characteristic (typical)

$R = f(T)$

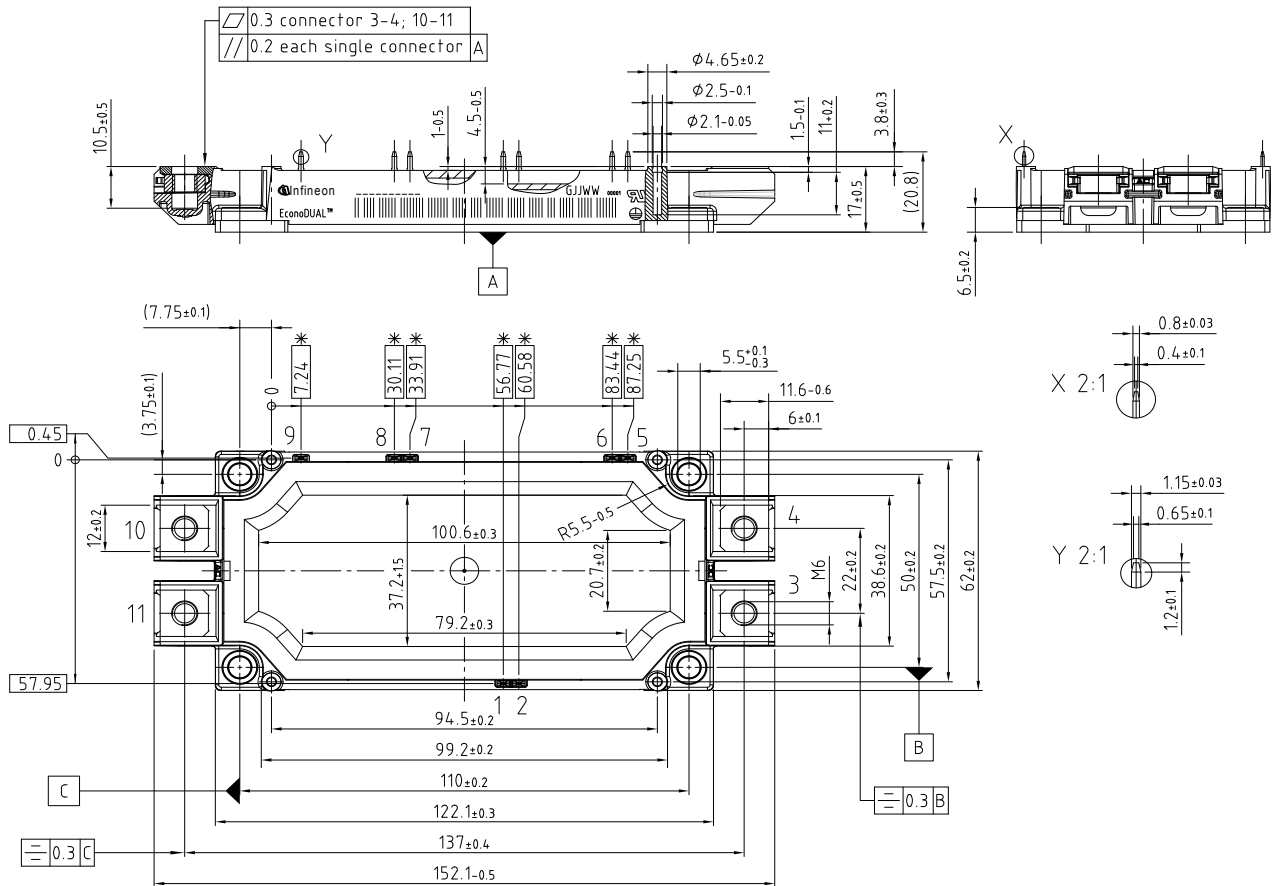


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| approved by: MK | revision: 3.1                   |

接线图 / circuit\_diagram\_headline



封装尺寸 / package outlines



\* = all dimensions with a tolerance of  $\pm 0.5$   
 dimensions valid in mounted condition

|                 |                                 |
|-----------------|---------------------------------|
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